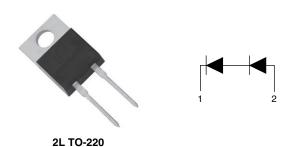
HALOGEN

FREE



#### Vishay Semiconductors

## Hyperfast Rectifier, 8 A FRED Pt®



PRODUCT SUMMARY					
Package	2L TO-220 Insulated				
I <sub>F(AV)</sub>	8 A				
$V_{R}$	600 V				
V <sub>F</sub> at I <sub>F</sub>	3.1 V				
t <sub>rr</sub> (typ.)	See Recovery table				
T <sub>J</sub> max.	175 °C				
Diode variation	Doubler				

#### **FEATURES**

- Hyperfast recovery time, extremely low Q<sub>rr</sub>
- Isolated TO-220 2 pin
- High frequency PFC CCM operation
- 175 °C maximum operating junction temperature
- Low leakage current
- Compliant to RoHS directive 2002/95/EC
- Halogen-free according to IEC 61249-2-21 definition
- Designed and qualified for industrial level

#### **DESCRIPTION**

VS-8S2TH06I-M 600 V series are the state of the art tandem hyperfast recovery rectifiers: the new insulated 2 pin TO-220 package provide benchmark thermal resistance that coupled with excellent switching performance and low forward voltage drop allow this device to provide 8 A DC at 120 °C case temperature.

Specially designed for CCM PFC application, these devices show incomparable performance in every current intensive hard switching application.

Optimized reverse recovery stored charge enables downsizing of boosting switch and cooling system. Increased operating frequency make possible use of smaller reactive elements. Cost effective PFC application is then possible with high efficiency over wide input voltage range and loading factor.

The new ceramic insulated package warranty insulation up to 2 kV and features easy mounting together with not insulated parts, with minimum effect on  $R_{thJC}$ .

ABSOLUTE MAXIMUM RATINGS FOR BOTH DIODES					
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS	
Repetitive peak reverse voltage	$V_{RRM}$		600	V	
DC forward current	I <sub>F</sub>	50 % duty cycle, rect. waveforms, T <sub>C</sub> = 120 °C	8	۸	
Non-repetitive peak surge current	I <sub>FSM</sub>	T <sub>C</sub> = 25 °C	140	А	
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		- 55 to 175	°C	

<b>ELECTRICAL SPECIFICATIONS FOR BOTH DIODES</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	SYMBOL TEST CONDITIONS		TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	Ι <sub>R</sub> = 100 μΑ	600	-	-		
Forward voltage V <sub>F</sub>	I <sub>F</sub> = 8 A	-	2.7	3.1	V		
	$V_{F}$	I <sub>F</sub> = 8 A, T <sub>J</sub> = 125 °C	-	2.1	2.3		
	I <sub>F</sub> = 8 A, T <sub>J</sub> = 150 °C	-	1.9	2.1			
		$V_R = V_R$ rated	-	< 1	10		
Reverse leakage current	I <sub>R</sub>	T <sub>J</sub> = 125 °C, V <sub>R</sub> = V <sub>R</sub> rated	-	7	50	μA	
		T <sub>J</sub> = 150 °C, V <sub>R</sub> = V <sub>R</sub> rated	-	27	80		
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 600 V	-	10.5	-	pF	

# VS-8S2TH06I-M

# Vishay Semiconductors Hyperfast Rectifier, 8 A FRED Pt®



Document Number: 93049 Revision: 19-Aug-10

<b>DYNAMIC RECOVERY CHARACTERISTICS FOR BOTH DIODES</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1.0 \text{ A}, dI_F/dt = -50 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	13	20	
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 8 A dI <sub>F</sub> /dt = - 200 A/μs V <sub>R</sub> = 390 V	-	11	16	ns
		T <sub>J</sub> = 125 °C		-	23	30	
Dook room ourrent	recovery current I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	1.5	2.5	А
Peak recovery current		T <sub>J</sub> = 125 °C		-	2.8	3.7	A
Reverse recovery charge Q <sub>rr</sub>	0	T <sub>J</sub> = 25 °C		-	7	15	nC
	T <sub>J</sub> = 125 °C		=	35	51	110	

THERMAL - MECHANICAL SPECIFICATIONS FOR BOTH DIODES						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 55	-	175	°C
Thermal resistance, junction to case	R <sub>thJC</sub>		-	2.30	2.85	°C/W
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	-	0.1	-	- C/VV
Approximate weight			-	2.0	-	g
Approximate weight			-	0.07	-	oz.
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)
Marking device		Case style 2L TO-220		8S2 <sup>-</sup>	TH06I	•



### Hyperfast Rectifier, 8 A FRED Pt® Vishay Semiconductors

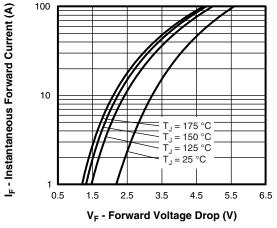


Fig. 1 - Typical Forward Voltage Drop Characteristics

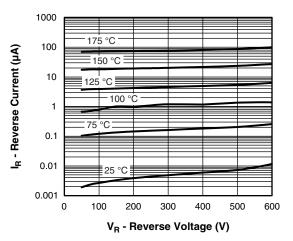


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

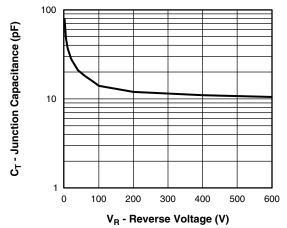


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

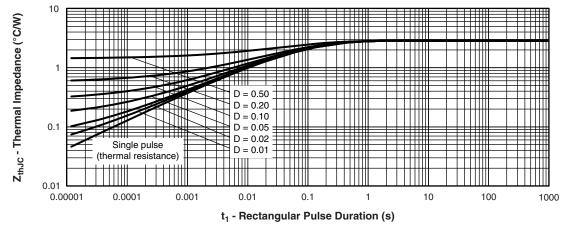


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

#### Vishay Semiconductors Hyperfast Rectifier, 8 A FRED Pt®



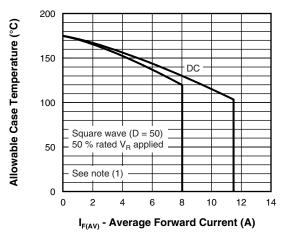


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

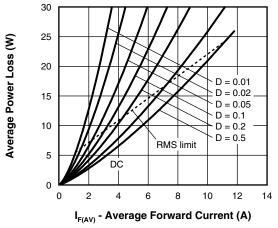


Fig. 6 - Forward Power Loss Characteristics

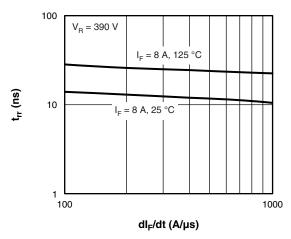


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

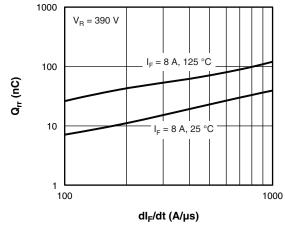


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

#### Note

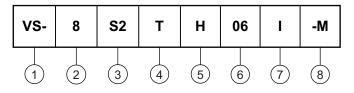
 $^{(1)}$  Formula used: T<sub>C</sub> = T<sub>J</sub> - (Pd +Pd<sub>REV</sub>) x R<sub>th,JC</sub>; Pd = Forward power loss = I<sub>F(AV)</sub> x V<sub>FM</sub> at (I<sub>F(AV)</sub>/D) (see fig. 6); Pd<sub>REV</sub> = Inverse power loss = V<sub>R1</sub> x I<sub>R</sub> (1 - D); I<sub>R</sub> at V<sub>R1</sub> = 50 % rated V<sub>R</sub>



### Hyperfast Rectifier, 8 A FRED Pt® Vishay Semiconductors

#### **ORDERING INFORMATION TABLE**

Device code



Vishay Semiconductors product suffix

2 - Current rating (8 = 8 A)

3 - S2 = Doubler true 2 pin

**4** - T = TO-220

5 - H = Hyperfast recovery

Voltage rating (06 = 600 V)

7 - I = Insulated

8 - Environmental digit:

-M = Halogen-free, RoHS compliant and terminations lead (Pb)-free

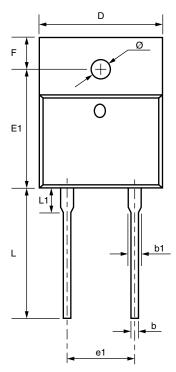
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95171			
Part marking information	www.vishay.com/doc?95170			
SPICE model	www.vishay.com/doc?95257			

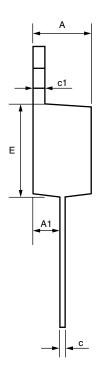


# Vishay High Power Products

#### TO-220-2L

#### **DIMENSIONS** in millimeters and inches





CVMPOL	MILLIN	IETERS	INCHES		
SYMBOL	MIN.	MAX.	MIN.	MAX.	
Α	4.420	4.720	0.174	0.186	
A1	2.520	2.820	0.099	0.111	
b	0.710	0.910	0.028	0.036	
b1	1.170	1.370	0.046	0.054	
С	0.360	0.460	0.014	0.018	
c1	1.170	1.370	0.046	0.054	
D	9.950	10.250	0.392	0.404	
Е	8.990	9.290	0.354	0.366	
E1	12.550	12.850	0.494	0.506	
e1	4.980	5.180	0.196	0.204	
F	2.59	2.89	0.102	0.114	
L	13.08	13.48	0.515	0.531	
L1	3.47	3.87	0.136	0.152	
Ø	3.79	3.89	0.149	0.153	



#### **Legal Disclaimer Notice**

Vishay

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Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

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